

Description

The TPS1120 uses advanced trench technology and design to provide excellent R_{DS(ON)} with low gat e charge. It can be used in a wide variety of applications.

General Features

 $V_{DS} = -20V, I_D = -4A$

 $R_{DS(ON)} < 95m\Omega @ V_{GS} = -4.5V$

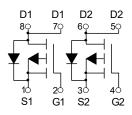
 $R_{DS(ON)} < 110 m\Omega @ V_{SS} = -2.5V$

Application

PWM application







Dual P-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
TPS1120	SOP-8	HXY MOSFET	3000

Absolute Maximum Ratings (T_A=25[°]C unless otherwise noted)

Symbol	Parameter	Limit	Unit
Vds	Drain-Source Voltage	-20	V
Vgs	Gate-Source Voltage	±12	V
lo	Drain Current-Continuous	-4	А
Ідм	Drain Current-Pulsed (Note 1)	-20	А
PD	Maximum Power Dissipation	2.0	W
Тј,Тѕтс	Operating Junction and Storage Temperature Range	-55 To 150	°C
Reja	Thermal Resistance, Junction-to-Ambient (Note 2)	62.5	°C /W



Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =-250uA	-20			V	
$\triangle BV_{\text{DSS}} / \triangle T_{\text{J}}$	BVDSS Temperature Coefficient	Reference to $25^\circ\!\mathrm{C}$, I _D =-1mA		-0.02		V/℃	
R _{DS(ON)}	Static Drain-Source On-Resistance ²	V _{GS} =-4.5V , b=-	5.8 A -	85	95	mΩ	
		V _{GS} =-2.5V , I _D =-3.5A		95	110	1115.2	
$V_{\text{GS(th)}}$	Gate Threshold Voltage	—	-0.6	-1.1	-1.7	V	
$ riangle V_{GS(th)}$	V _{GS(th)} Temperature Coefficient	VGS-VDS, ID2500A		4.32		mV/℃	
1	Drain-Source Leakage Current	V_{DS} =-16V , V_{GS} =0V , T_{J} =25 $^{\circ}$ C			-1	- uA	
I _{DSS}		V_{DS} =-16V , V_{GS} =0V , T _J =55 $^{\circ}$ C			-5		
I _{GSS}	Gate-Source Leakage Current	$V_{GS}=\pm20V$, $V_{DS}=0V$			±100	nA	
gfs	Forward Transconductance	V _{DS} =-5V , I _D =-3A		5.5		S	
R_g	Gate Resistance	V_{DS} =0V , V_{GS} =0V , f=1MHz		24	48	Ω	
Qg	Total Gate Charge (-4.5V)			10.6	15		
Q_{gs}	Gate-Source Charge	V_{DS} =-16V , V_{GS} =-4.5V , I_{D} =-5.8A		1.0		nC	
Q_gd	Gate-Drain Charge			2.0			
T _{d(on)}	Turn-On Delay Time			10	12		
Tr	Rise Time	V_{DD} =-15V , V_{GS} =-10V , R_{G} =6 Ω		4.9	6	ns	
$T_{d(off)}$	Turn-Off Delay Time	I _D =-1A, RG=10Ω		22	42		
T _f	Fall Time			3	9		
C _{iss}	Input Capacitance			325			
C _{oss}	Output Capacitance	V _{DS} =-15V , V _{GS} =0V , f=1MHz		60		pF	
C _{rss}	Reverse Transfer Capacitance			30			
ls	Continuous Source Current ^{1,4}	−−−V _G =V _D =0V , Force Current			-2.0	А	
I _{SM}	Pulsed Source Current ^{2,4}				-20	А	
V_{SD}	Diode Forward Voltage ²	V _{GS} =0V , I _S =-1.7A , TJ=25℃			-1	V	

Electrical Characteristics (T_J=25 °C, unless otherwise noted)

Note :

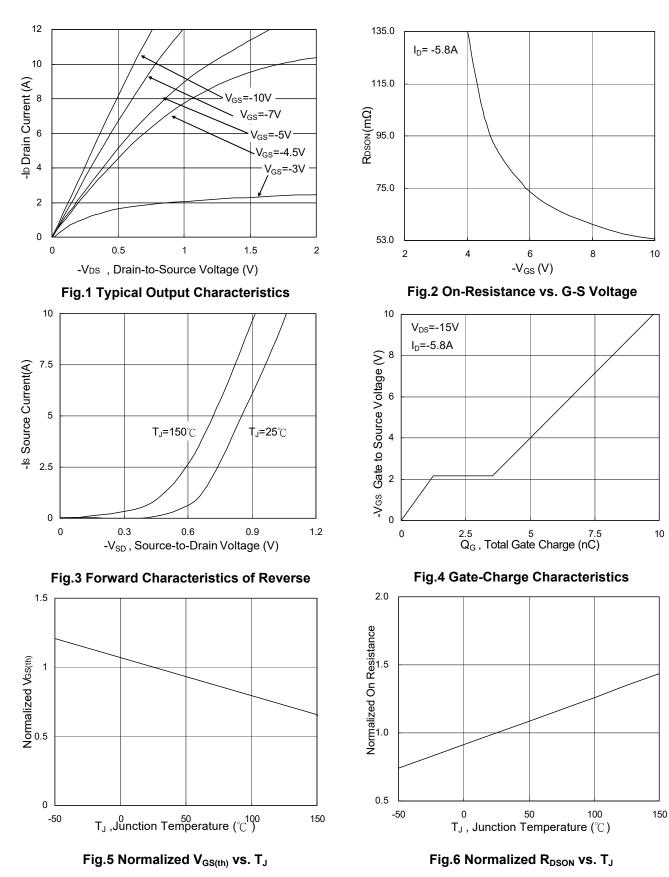
1. The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper,t<10sec.

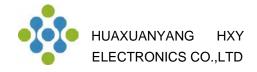
2.The data tested by pulsed , pulse width $\leq 300 us$, duty cycle $\leq 2\%$ 3.The power dissipation is limited by 150 $^\circ\!C$ junction temperature

4. The data is theoretically the same as I_D and I_{DM} , in real applications, should be limited by total power dissipation.



Typical Characteristics





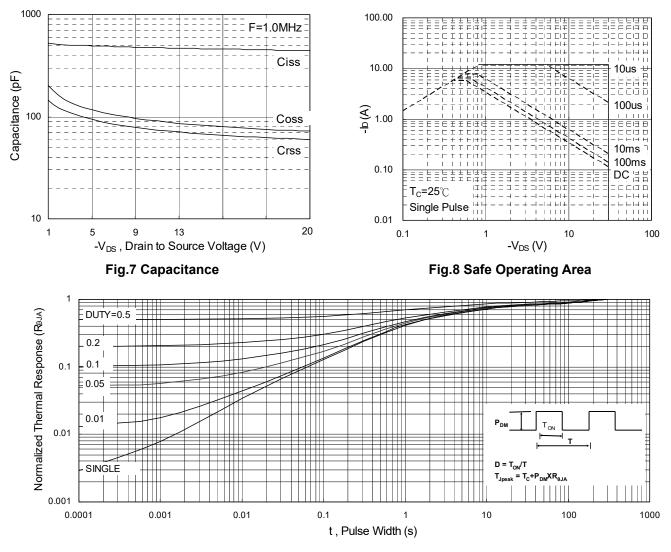


Fig.9 Normalized Maximum Transient Thermal Impedance

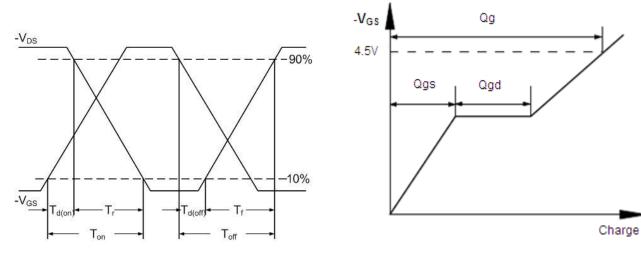
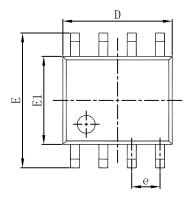


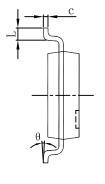
Fig.10 Switching Time Waveform

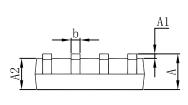
Fig.11 Gate Charge Waveform



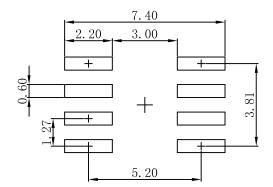
SOP-8 Package Outline Dimensions







Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
А	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
с	0.170	0.250	0.007	0.010	
D	4.800	5.000	0.189	0.197	
e	1.270 (BSC)		0.050 (BSC)		
E	5.800	6.200	0.228	0.244	
E1	3.800	4.000	0.150	0.157	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0 °	8°	



- Note: 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.



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